## ATTACHMENT B Amendments to the Claims

Please cancel claims 3 and 4 without prejudice or disclaimer.

This listing of claims will replace all prior versions, and listings, of claims in the application.

- 1. (Currently amended) An etching solution comprising:
- (i) hydrofluoric acid;
- (ii) water in a concentration of 30% by weight or lower; and
- (iii) at least one member selected from the group consisting of an organic acid, an inorganic acid and an organic solvent having a hetero atom, whose content ranges from 30 to 99.9% by weight,

wherein the etching solution has a ratio of an etch rate of a boron silicate glass film (BSG) or boron phosphosilicate glass / an etch rate of a thermal oxide film (THOX) at 25°C-is of 20 or higher.

- 2. (Currently Amended) The etching solution according to claim 1, wherein-a the organic solvent-in the etching solution has a relative dielectric constant of 61 or lower.
  - 3. (Cancel)
  - 4. (Cancel)

- 5. (Currently Amended) The etching solution according to claim 1, wherein the weight the organic solvent is isopropyl alcohol and the etching solution has a constituent ratio of HF: isopropyl alcohol: water-is by 0.1-50% by weight: 30-99% by weight: 0-70% by weight.
- 6. (Currently Amended) The etching solution according to claim 1, wherein the weight the organic acid is acetic acid and the etching solution has a constituent ratio of HF: acetic acid: water is 0.1-50% by weight: 30-99.9% by weight: 0-70% by weight.
- 7. (Currently Amended) The etching solution according to claim 1, wherein the weight the organic solvent comprises tetrahydrofuran and the etching solution has a constituent ratio of HF: tetrahydrofuran: water is 0.1-50% by weight: 30-99.9% by weight: 0-70% by weight.
- 8. (Currently Amended) The etching solution according to claim 1, wherein the weight the organic solvent is acetone and the etching solution has a constituent ratio of HF: acetone: water is 0.1-50% by weight: 30-99.9% by weight: 0-70% by weight.
- 9. (Currently Amended) The etching solution according to claim 1, wherein the weight the organic solvent comprises methanol and the etching solution has a constituent ratio of HF: methanol: water is 0.1-50% by weight: 30-99.9% by weight: 0-70% by weight.

- 10. (Currently Amended) The etching solution according to claim 1, wherein the weight the organic solvent comprises ethanol and the etching solution has a constituent ratio of HF: ethanol: water is 0.1-50% by weight: 30-99.9% by weight: 0-70% by weight.
- 11. (Currently Amended) The etching solution according to claim 1, the solution comprising wherein the solution comprises an inorganic acid.
- 12. (Original) The etching solution according to claim 11, wherein the inorganic acid has a pKa value at 25°C of 2 or lower.
- 13. (Currently Amended) The etching solution according to claim 11, wherein the weight the inorganic acid is HCl and the etching solution has a constituent ratio of HF: HCl: water is 0.01-50% by weight: 1-36% by weight: 0-99% by weight.
- 14. (Currently Amended) The etching solution according to claim 11, wherein the weight the inorganic acid is HNO<sub>3</sub> and the etching solution has a constituent ratio of HF: HNO<sub>3</sub>: water is 0.01-50% by weight: 1-70% by weight: 0-99% by weight.
- 15. (Previously Presented) A method for producing an etched article by etching an article to be etched with the etching solution as defined in claim 1.
  - 16. (Original) An etched article which is obtainable by the method of claim 15.